### Notification about the transfer of the semiconductor business

The semiconductor business of Panasonic Corporation was transferred on September 1, 2020 to Nuvoton Technology Corporation (hereinafter referred to as "Nuvoton"). Accordingly, Panasonic Semiconductor Solutions Co., Ltd. became under the umbrella of the Nuvoton Group, with the new name of Nuvoton Technology Corporation Japan (hereinafter referred to as "NTCJ").

In accordance with this transfer, semiconductor products will be handled as NTCJ-made products after September 1, 2020. However, such products will be continuously sold through Panasonic Corporation.

Publisher of this Document is NTCJ.

If you would find description "Panasonic" or "Panasonic semiconductor solutions", please replace it with NTCJ.

\* Except below description page

"Request for your special attention and precautions in using the technical information and semiconductors described in this book"

Nuvoton Technology Corporation Japan

## Panasonic

MOS FET FC4B21080L

### FC4B21080L Gate resistor installed Dual N-channel MOS FET

For lithium-ion secondary battery protection circuits

#### Features

- Low source-source ON resistance:Rss(on) typ. = 27 mΩ(VGS = 4.5 V)
- CSP package:smallest & thinnest size
- RoHS compliant (EU RoHS / MSL:Level 1 compliant)
- Marking Symbol: 12

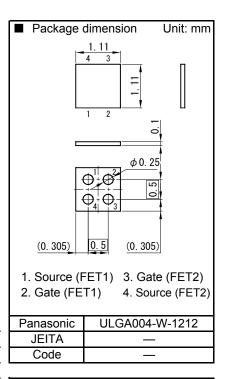
#### Packaging

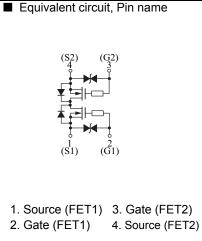
Embossed type (Thermo-compression sealing) : 20 000 pcs / reel (standard)

■ Absolute Maximum Ratings Ta = 2	5 °C		
Parameter	Symbol	Rating	Unit
Source-source Voltage	VSS	12	V
Gate-source Voltage	VGS	±12	V
Source Current (DC) <sup>*1</sup>	IS	2.9	А
Source Current (Pulsed) *1,*2	ISp	29	А
Total Power Dissipation *1	PD	0.35	W
Channel Temperature	Tch	150	°C
Storage Temperature Range	Tstg	-55 to +150	°C
Thermal resistance (ch-a)	Rth(ch-a)	352	°C/W
Note *1 Mounted on EB4 board (25.4 mm v	$25.4 \text{ mm} \times t1$	0 mm)	

Note \*1 Mounted on FR4 board (25.4 mm  $\times$  25.4 mm  $\times$  t1.0 mm)

using the minimum recommended pad size(Cu area = 47 mm2 including traces). \*2 t = 10  $\mu$ s, Duty Cycle  $\leq$  1 %







## MOS FET FC4B21080L

■ Electrical Characteristics Ta = 25 °C ± 3 °C

Parameter	Symbol	Conditions	Min	Тур	Max	Unit	
Source-source Breakdown Voltage	VSSS	IS = 1 mA, VGS = 0 V	12			V	
Zero Gate Voltage Source Current	ISSS	VSS = 12 V, VGS = 0 V			1.0	μA	
Gate-source Leakage Current	IGSS	VGS = ±8 V, VSS = 0 V			±10	μA	
	1000	VGS = ±5 V, VSS = 0 V			±1.0	μA	
Gate-source Threshold Voltage	Vth	IS = 1.0 mA, VSS = 10 V	0.4	0.85	1.4	V	
Source-source On-state Resistance		IS = 1.5 A, VGS = 4.5 V	18	27	37	mΩ	
	RSS(on)2	IS = 1.5 A, VGS = 3.8 V	21	30	41.5		
	RSS(on)3	IS = 1.5 A, VGS = 3.1 V	23	39	64		
	RSS(on)4	IS = 1.5 A, VGS = 2.5 V	30	60	100		
Input Capacitance <sup>*1</sup>	Ciss			850			
Output Capacitance <sup>*1</sup>	Coss	VSS = 10 V, VGS = 0 V, f = 1 MHz		205		pF	
Reverse Transfer Capacitance <sup>*1</sup>	Crss			203			
Turn-on delay Time *1,*2	td(on)	VDD = 10 V, VGS = 0 to 4.0 V		0.6			
Rise Time <sup>*1,*2</sup>	tr	IS = 1.5 A		1.7		μS	
Turn-off delay Time *1,*2	td(off)	VDD = 10 V, VGS = 4.0 to 0 V 2.6					
Fall Time *1,*2	tf	IS = 1.5 A		3.1		μS	
Total Gate Charge <sup>*1</sup>	Qg	VDD = 10 V		7.1			
Gate-source Charge <sup>*1</sup>	Qgs	VGS = 0 to 4.0 V,		1.5		nC	
Gate-drain Charge <sup>*1</sup>	Qgd	IS = 2.9 A		2.7		L	
Body Diode Forward Voltage	VF(s-s)	IF = 2.9 A, VGS = 0 V		0.8	1.2	V	

Note Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 Measuring

methods for transistors.

\*1 Assured by design

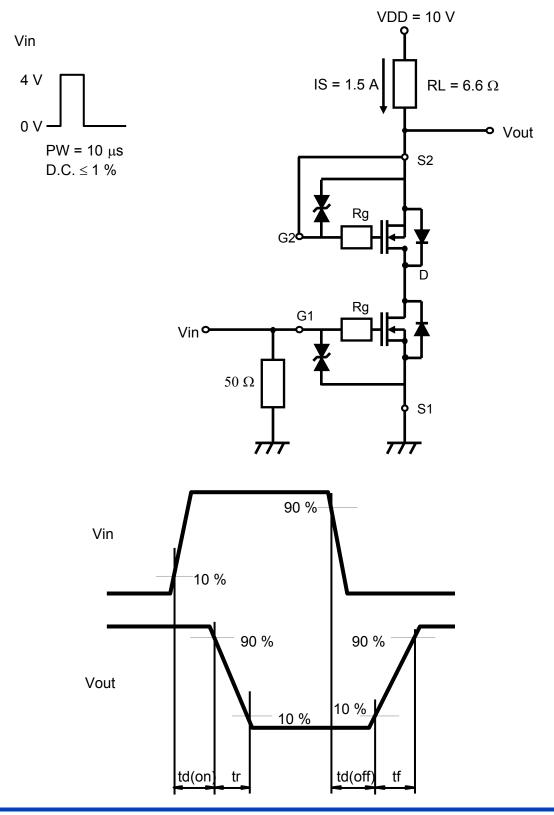
\*2 Measurement circuit for Turn-on Delay Time / Rise Time / Turn-off Delay Time / Fall Time

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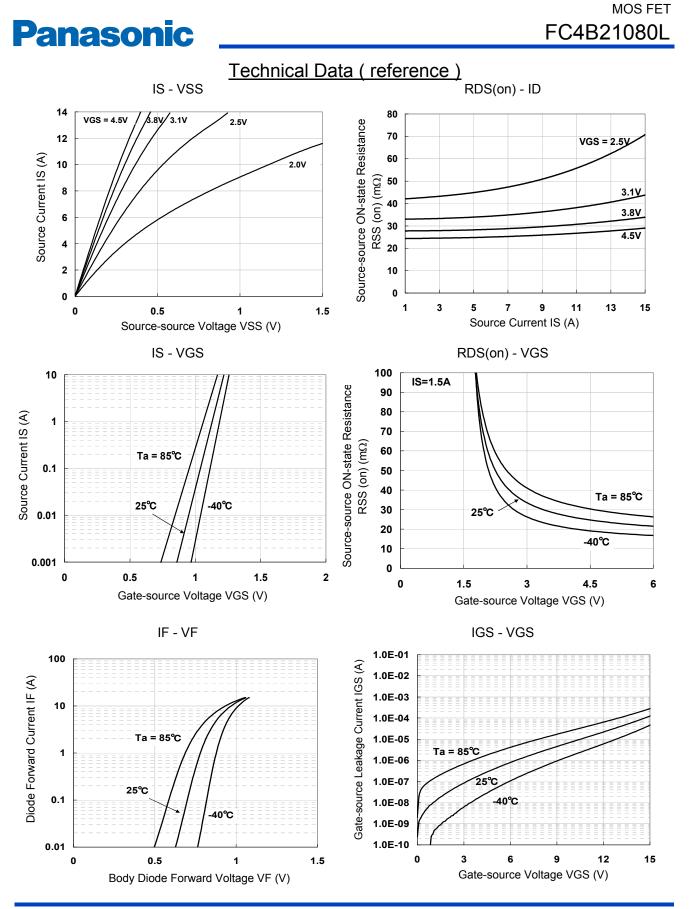


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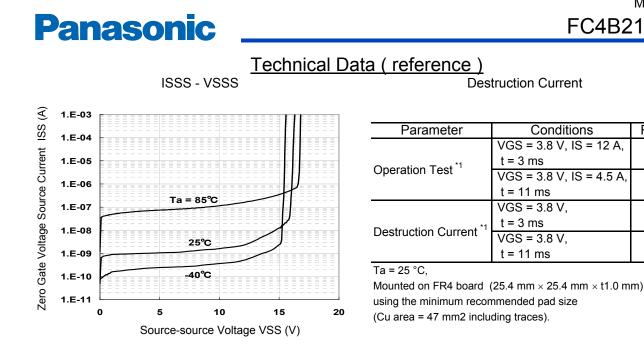
\*2 Measurement circuit for Turn-on delay time / Rise time / Turn-off delay time / Fall time



Established : 2012-04-19 Revised : 2012-12-07







# FC4B21080L

Result

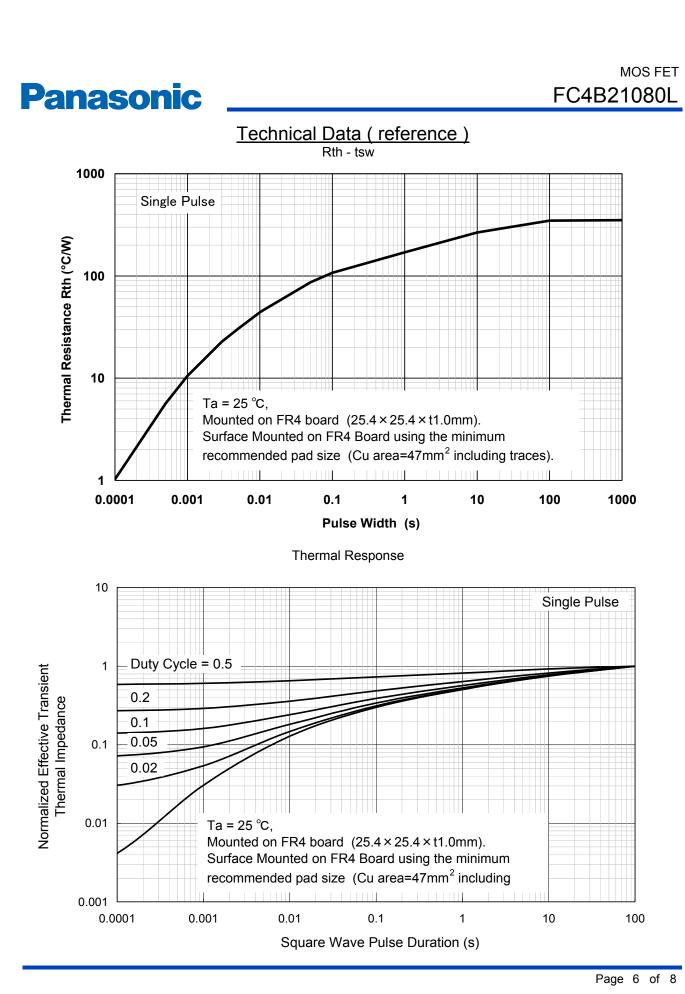
PASS

PASS

31 A

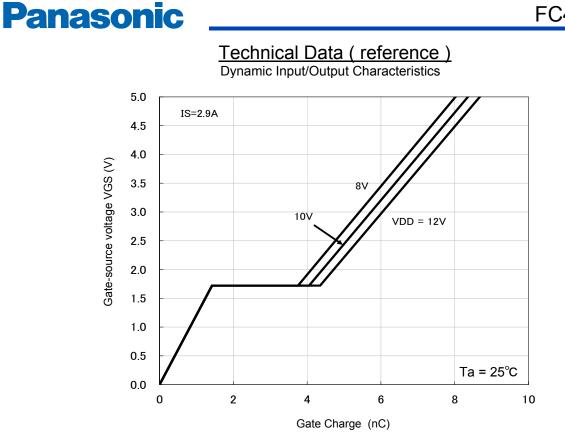
16 A

MOS FET

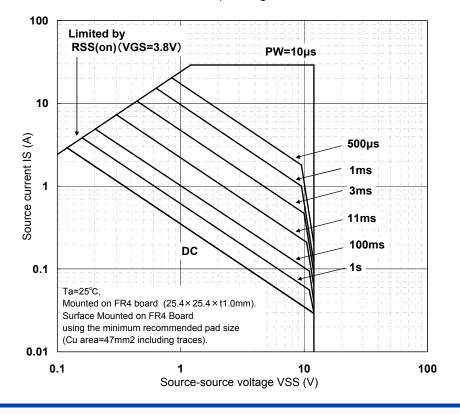


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## MOS FET FC4B21080L



Safe Operating Area



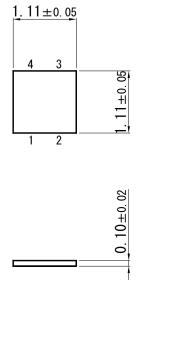
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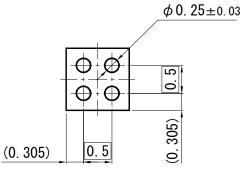


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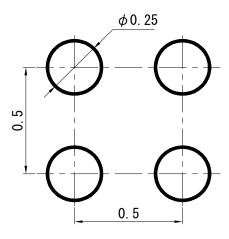
### ULGA004-W-1212

Unit: mm





Land Pattern (Reference) (Unit: mm)



Established : 2012-04-19 Revised : 2012-12-07

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